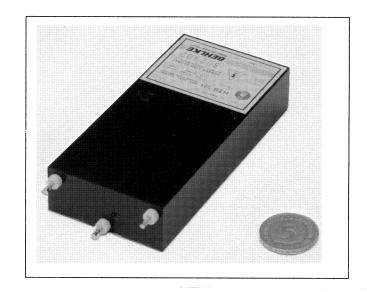
FAST HIGH VOLTAGE TRANSISTOR SWITCHES

Description

This solid-state switch has been designed for high voltage, high speed switching applications such as acceleration and deflection grid drivers, pockels cell drivers, power tube drivers and high-voltage pulse generators. In contrast to conventional high voltage switches like thyratrons, the HTS 121 is a very universal, small and light-weight switching element, which does not need heating power or a complex drive circuitry. The HTS 121 has a very short recovery time, a high repetition rate, a low jitter and a lifetime typical of semiconductor devices. The power part of switch is made up of a large number of MOSFET connected in parallel and in series which are controlled absolutely synchronously by a special driver circuit. The on-time of the switch is proportional to the input signal and can be controlled between 150 ns and infinity. That means the switch remains turned on as long as the TTL control input is set at high. The turn-on rise time depends essentially on the operating voltage and the load capacitance. Due to the galvanic isolation of more than 18 kVDC, the HTS 121 can be used as high-side switch for positive as well as for negative voltages without any isolation transformer or opto coupler. The device is protected from thermal overload by means of an internal temperature sensor. Further protection is afforded against too high a signal frequency, unsuitable control signals and an unsuitable auxiliary supply.

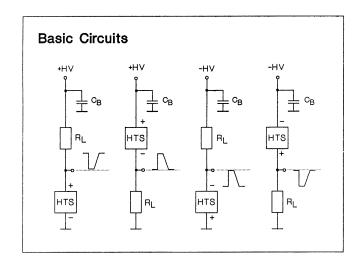
For detailed design recommendations please refer to the "General Instructions for Use".

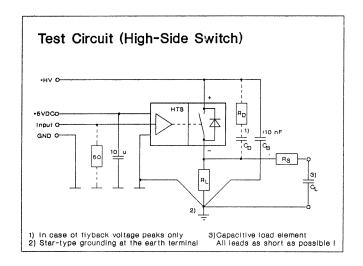
HTS 121 12000 Volts / 30 Amps Variable On-Time Simple Connection Compact Design

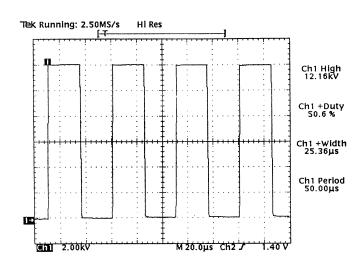


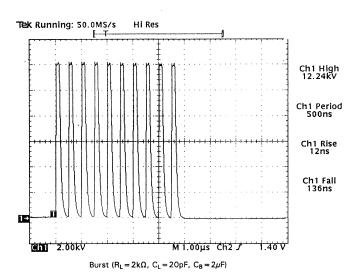
SPECIFICATION	SYMBOL	CONDITION / COMMENT	HTS 121	UNIT
Maximum Operating Voltage	V _{O(max)}		±12000	VDC
Switch Breakdown Voltage	V_{br}	$I_{off} = 1 \text{ mADC}, T_{case} = 70^{\circ}\text{C}$	>14000	VDC
Isolation Voltage	VI	HV side against control side	>18000	VDC
Maximum Peak Current	I _{P(max)}	$t_p < 10 \mu s$, duty cycle $< 1\%$	30	ADC
Max. Continuous Load Current	IL	$T_{case} = 25$ °C (Surface temperatur	e) 0.8	ADC
Static On-Resistance	R _{stat}	$I_L = 0.1 \times I_{P(max)}$	30	
		$I_L = I_{P(max)}$	90	Ω
Maximum Off-State Current	I _{off}	0.8 x V ₀	<15	μADC
Turn-On Delay Time	t _{d(on)}	$0.8 \times V_0$, $C_L = 20 \text{ pF}$, $R_S = 51\Omega$	100	ns
Turn-On Rise Time	t _{r(on)}	$0.5 \times V_0, C_L = 20 \text{ g}$	pF 7	
		$R_L = 10K$ $0.8 \times V_0$, $C_L = 20 \text{p}$	oF 10	
		$R_S = 51\Omega$ 0.8 x V_O , $C_L = 100 \text{p}$	oF 28	
		$0.8 \times V_0, C_L = 500 \text{p}$	oF 75	ns
Turn-Off Time	t _(off)	Actual trailing edge is determined	by R _L xC _L <10	ns
Typical Turn-On Jitter	t _{j(on)}	$V_{aux} = 5.0 \text{ VDC}, V_{tr} = 5 \text{VDC}, f = 1 \text{kl}$	Hz 100	ps
On-Time Range	t _{on}		150 ns to infinity	
Maximum Burst Frequency	f _{b(max)}	Use option 01 for $>$ 20 pulses / 2	0μs burst 3	MHz
Maximum Continuous Frequency	f _{c(max)}	@ $V_{aux} = 5.00 \text{ VDC}$, note $P_{d(max)}$	limitations 20	kHZ
Continuous Power Dissipation	P _{d(max)}	$T_{case} = 25$ °C, derating 0.44 W/°C	C above 25°C 20	Watts
Temperature Range	To	Extented temperature range on rec	uest -30 to +70	°C
Switch Natural Capacitance	C _N	Capacitance between switch poles	s at V _{O(max)} 30	pF
Coupling Capacitance	C _C	Power side against control side	25	pF
Diode Reverse Recovery Time	t _{rrc}	@ I _F =6A, Caution: Diode must no	t be used! 1	μs
Auxiliary Supply Voltage	V _{aux}	Stabilized to ± 5%	5	VDC
Auxiliary Supply Current	l _{aux}	@ fc _(max)	400	mADC
Control Voltage	V _{tr}		2-10	VDC
Dimensions		Case only, see drawing	135x64x27	mm ³
Weight			400	g

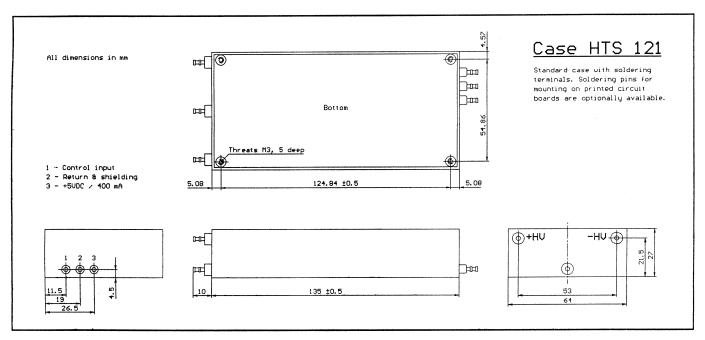












Ordering Informations:

HTS 121 Option 01 High Voltage Transistor Switch High Frequency Burst (Connections

for external buffer capacitors)

Option 02

UL 94-VO Casting Resin

Option 03

Soldering Pins for PCB mounting

All data and specifications subject to change without notice. Custom designed devices on request.